

# Operational experience and performance of the Belle II Silicon Vertex Detector after the first SuperKEKB Long Shutdown

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Belle II Silicon Vertex Detector

## SuperKEKB

- 7 GeV  $e^-$ , 4 GeV  $e^+$ ,  $\sqrt{s} = 10.58$  GeV for  $\Upsilon(4S)$
- Target integrated luminosity 50  $\text{ab}^{-1}$
- Target instantaneous luminosity  $6 \times 10^{35} \text{ cm}^{-2} \text{ s}^{-1}$

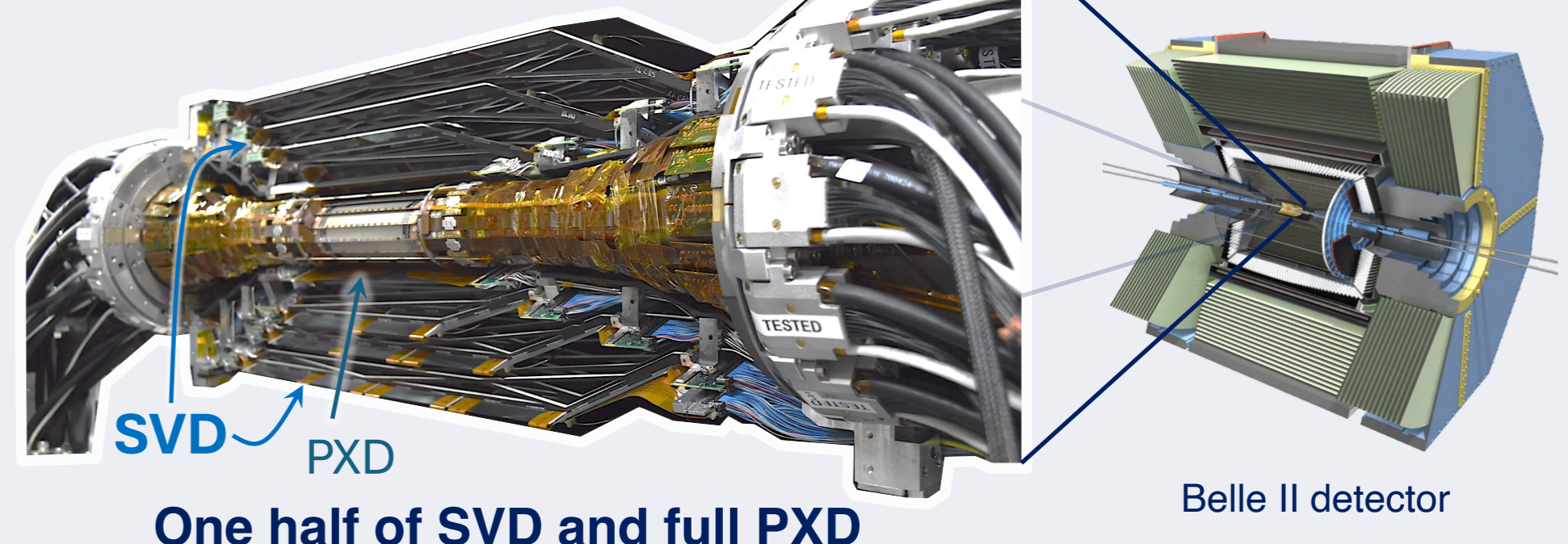
## Belle II

- Measures phenomena from the beam collision provided by SuperKEKB
- searches for new physics beyond the standard model at the luminosity frontier

## Belle II Silicon Vertex Detector (SVD)

- 4 layers of the Double-Sided Silicon Detector, strip pitch ( $\mu\text{m}$ ): 50/75 (P side,  $r\phi \equiv u$ ), 160/240 (N side,  $z \equiv v$ )
- Thickness:  $\sim 320 \mu\text{m}$
- Constitute VXD with 2 layers of DEPFET pixel detector (PXD); inner PXD 2 layer + outer 4 SVD layer
- Readout ASIC: APV25, shaping time 50 ns
- Cooling: two-phase  $\text{CO}_2$  flow
- Provides precise hit information to reconstruct track, reconstruct vertex, particle identification with  $dE/dx$

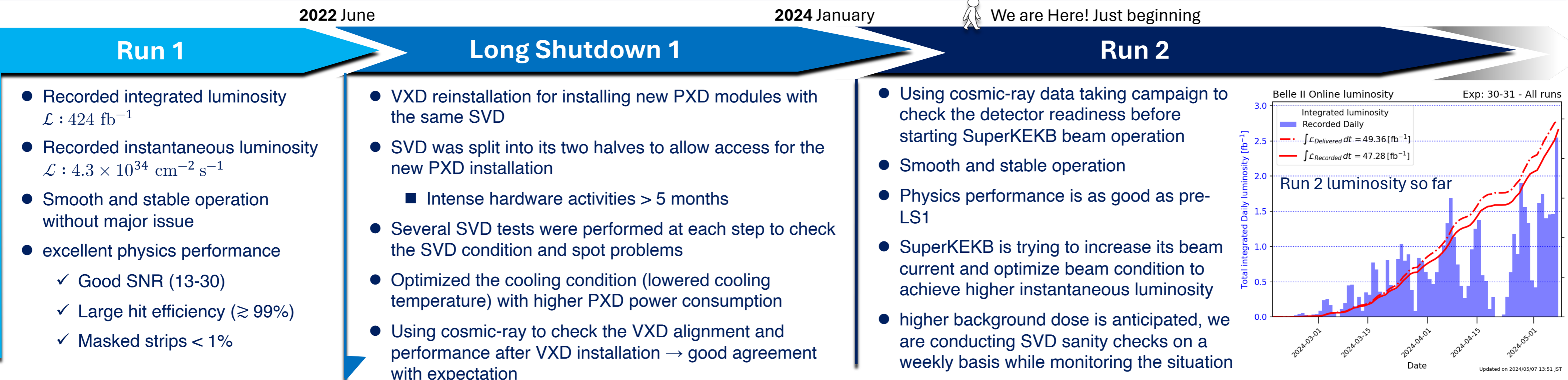
Belle II Vertex Detector: VXD = SVD + PXD



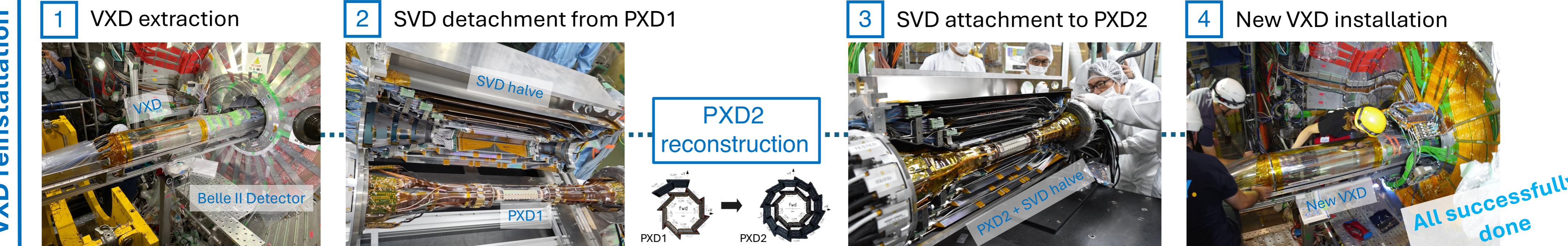
One half of SVD and full PXD

Belle II detector

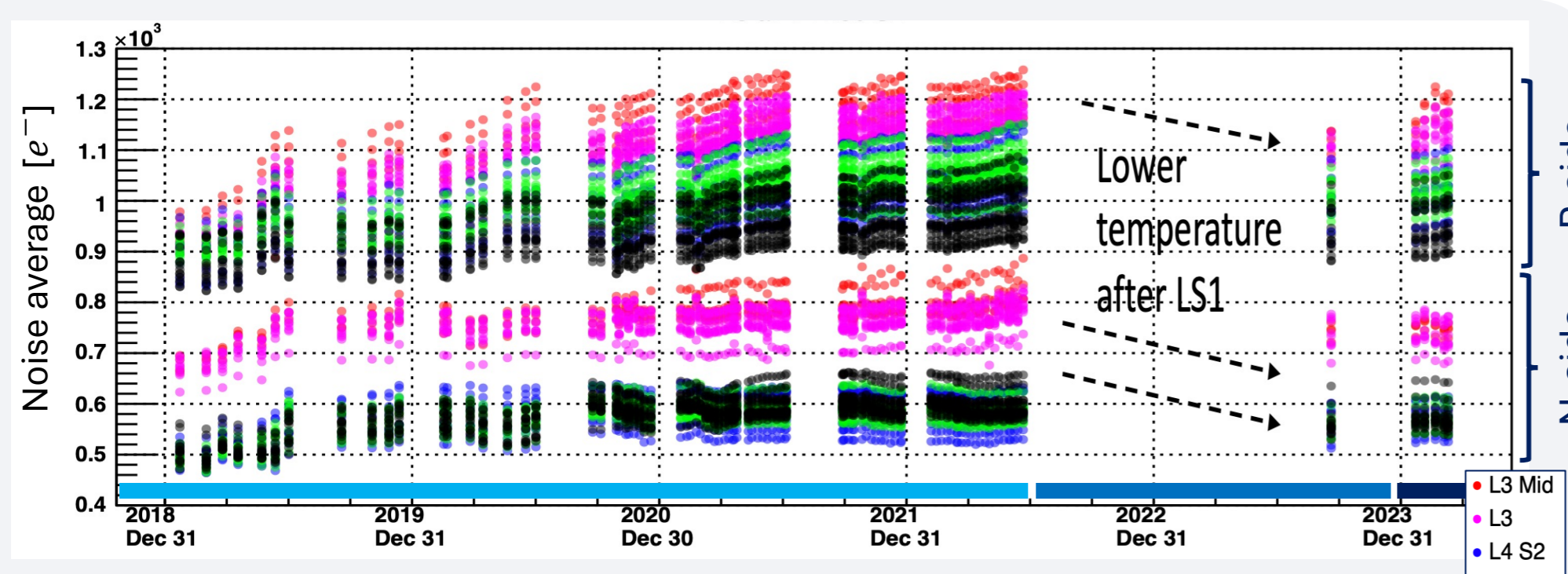
Timeline and operations



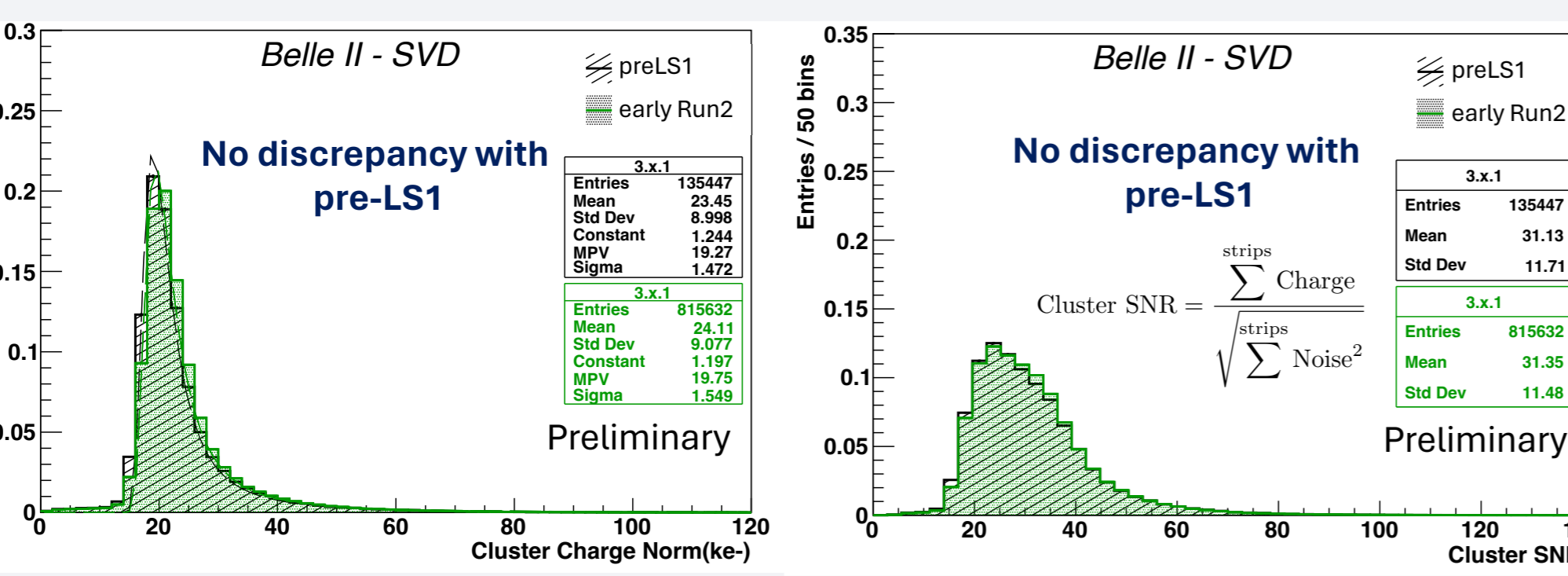
VXD reinstallation



SVD performance after LS1



- Noise increased 10 ~ 30% during Run 1 due to radiation damage on the sensor
  - Measured radiation dose of Run 1 in Layer 3 is < 70 krad
- Reduction in noise by up to 10% during LS1 due to lower operating temperature and annealing effect on the sensor
- Noise has resumed its escalation from the beginning of Run 2



- No degradation in the cluster charge collection level and cluster SNR from Run 1, both are the expected level. Hit efficiency also keeps high  $\geq 99\%$
- Masked additional few noisy strips that appeared after a large beam abort, but still total masked strips < 1%
- No change found in the full depletion voltage due to radiation damage so far

Radiation damage study

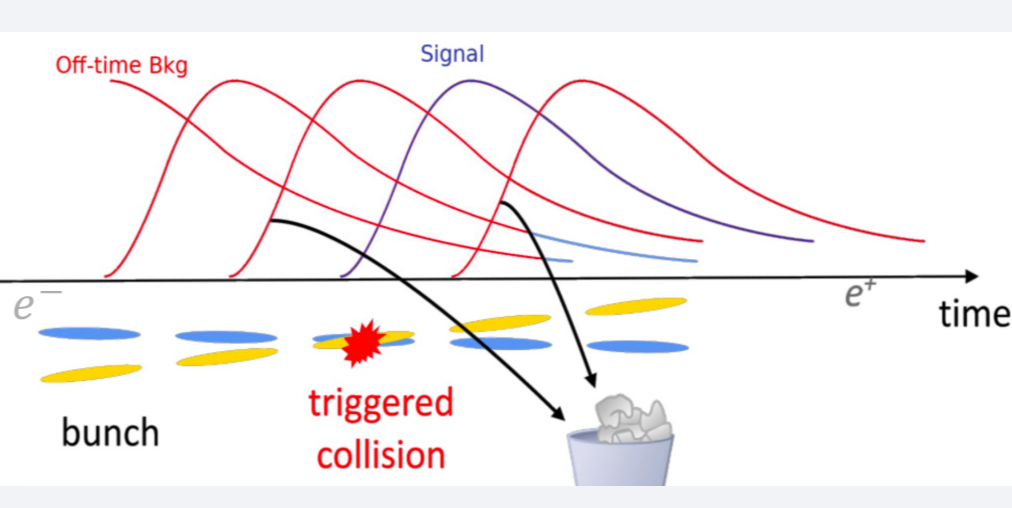
- Sensor Irradiation campaign: 90 MeV  $e^-$  beam at ELPH, Tohoku Univ, July 2022 up to 10 Mrad
  - ✓ Observed the full depletion voltage change with large dose s.t. > 0.4 Mrad
  - ✓ Type inversion occurs at 2 Mrad, equivariant neutron fluence  $6 \times 10^{12} n_{\text{eq}}/\text{cm}^2$
  - ✓ irradiated sensors confirmed to work with collecting charge well after type inversion
  - ✓ Linear correlation between dose and leakage current as NIEL hypothesis
  - ✓ the correlation is also confirmed in the operating sensors and the slope of dose vs leakage current is consistent

Estimated radiation dose: < 0.2 Mrad/year, we have a good safety margin

Future background rejection

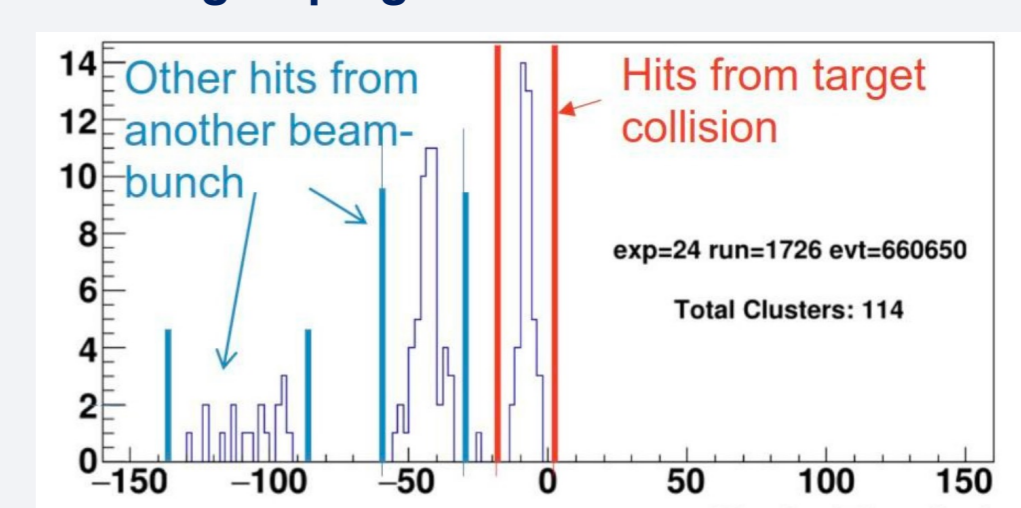
- current hit occupancy is below 1%, but it is expected to rise as the background increases with higher beam luminosity in the future
- Higher occupancy will degrade tracking performance such that an increase of fake tracks.
- We will implement hit-time selection and cluster grouping methods, which are based on hit time to reject background and enhance occupancy acceptance
  - Hit time measured with reference to the collision event time ( $T_0$ ) provided by the central drift chamber (CDC) now
  - SVD also has the same feature but offers a 2000 times faster computing speed to provide  $T_0$ . It speeds up the High Level Trigger (HLT) reconstruction and helps it cope with HLT reconstruction in the high luminosity condition.

### Hit-time selection

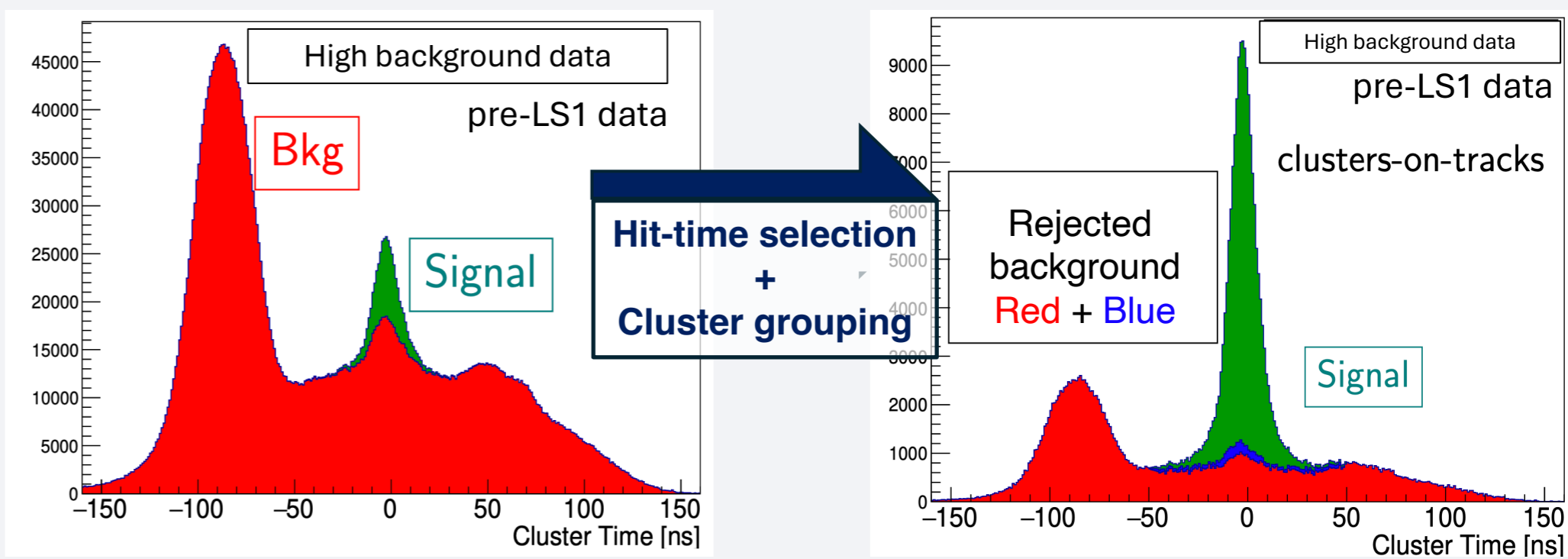


- With excellent hit time resolution (< 3 ns) remove off-time tracks
  - $|t_{u,v}| < 50 \text{ ns}$
  - $|t_u - t_v| < 20 \text{ ns}$

### Cluster grouping



- Classified hit time on trigger event by event basis.
- Select a group close to 0 and prominent as a signal group to form tracks



- Hit-time selection can reject the red background region and the cluster grouping can reject the blue background region in the right figure above. These improvements lead to an increase in occupancy acceptance to about 6% for Layer 3.

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